

2MBI400N-060-01

IGBT Module

600V / 400A 2 in one-package

Features

- VCE(sat) classified for easy parallel connection
- High speed switching
- Voltage drive
- Low inductance module structure

Applications

- Inverter for Motor drive
- AC and DC Servo drive amplifier
- Uninterruptible power supply
- Industrial machines, such as Welding machines

Maximum ratings and characteristics

Absolute maximum ratings (at Tc=25°C unless otherwise specified)

Item	Symbol	Rating	Unit
Collector-Emitter voltage	V _{CES}	600	V
Gate-Emitter voltage	V _{GES}	±20	V
Collector current	Continuous	I _C	400
	1ms	I _C pulse	800
		-I _C	400
	1ms	-I _C pulse	800
Max. power dissipation	P _C	1500	W
Operating temperature	T _j	+150	°C
Storage temperature	T _{stg}	-40 to +125	°C
Isolation voltage	V _{is}	AC 2500 (1min.)	V
Screw torque	Mounting *1	3.5	N·m
	Terminals *2	4.5	N·m

*1 Recommendable value : 2.5 to 3.5 N·m (M5) or (M6)

*2 Recommendable value : 3.5 to 4.5 N·m

Electrical characteristics (at Tj=25°C unless otherwise specified)

Item	Symbol	Characteristics			Conditions	Unit
		Min.	Typ.	Max.		
Zero gate voltage collector current	I _{CES}	—	—	2.0	V _{GE} =0V, V _{CE} =600V	mA
Gate-Emitter leakage current	I _{GES}	—	—	30	V _{CE} =0V, V _{GE} =±20V	μA
Gate-Emitter threshold voltage	V _{GE(th)}	4.5	—	7.5	V _{CE} =20V, I _C =400mA	V
Collector-Emitter saturation voltage	V _{CE(sat)}	1.8	—	2.8	V _{GE} =15V, I _C =400A	V
Input capacitance	C _{ies}	—	26400	—	V _{GE} =0V	pF
Output capacitance	C _{oes}	—	5870	—	V _{CE} =10V	
Reverse transfer capacitance	C _{res}	—	2670	—	f=1MHz	
Turn-on time	t _{on}	—	0.6	1.2	V _{CC} =300V	μs
	t _r	—	0.2	0.6	I _C =400A	
Turn-off time	t _{off}	—	0.6	1.0	V _{GE} =±15V	
	t _f	—	0.2	0.35	R _G =4.7ohm	
Diode forward on voltage	V _F	—	—	3.0	I _F =400A, V _{GE} =0V	V
Reverse recovery time	t _{rr}	—	—	0.3	I _F =400A	μs

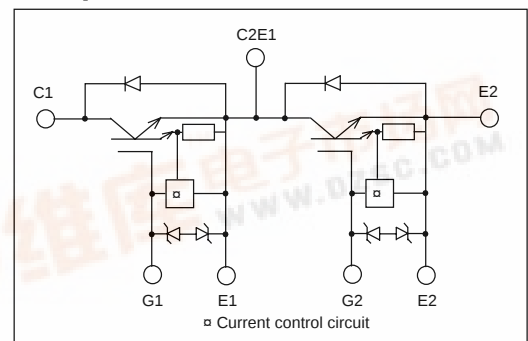
Thermal resistance characteristics

Item	Symbol	Characteristics			Conditions	Unit
		Min.	Typ.	Max.		
Thermal resistance	R _{th(j-c)}	—	—	0.085	IGBT	°C/W
	R _{th(j-c)}	—	—	0.15	Diode	°C/W
	R _{th(c-f)*}	—	0.025	—	the base to cooling fin	°C/W

* This is the value which is defined mounting on the additional cooling fin with thermal compound



Equivalent Circuit Schematic

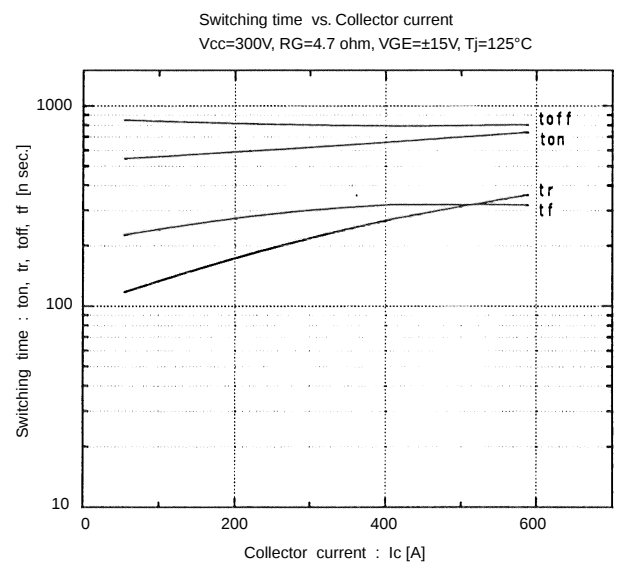
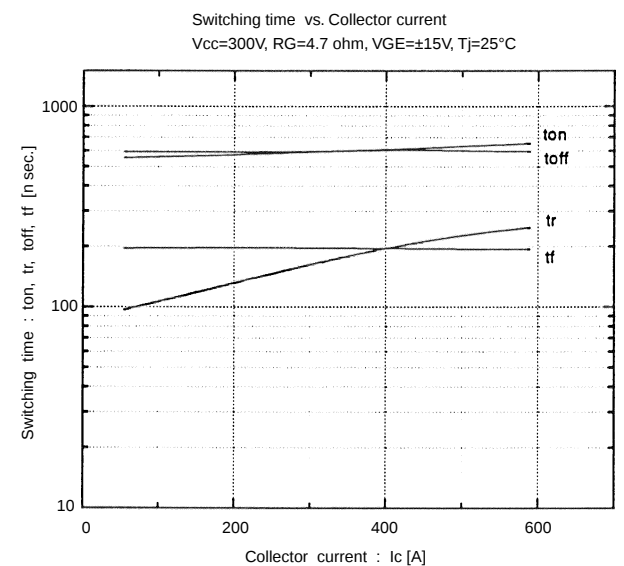
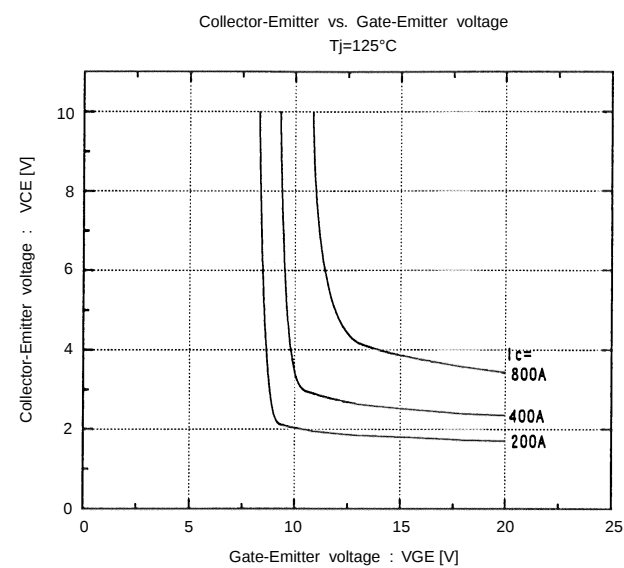
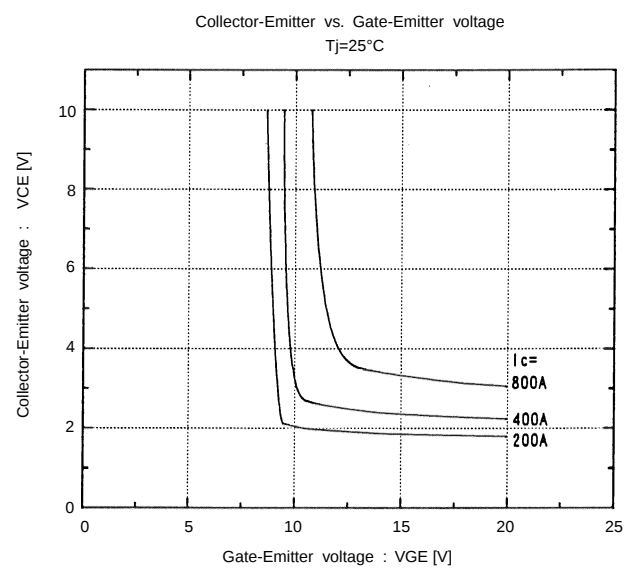
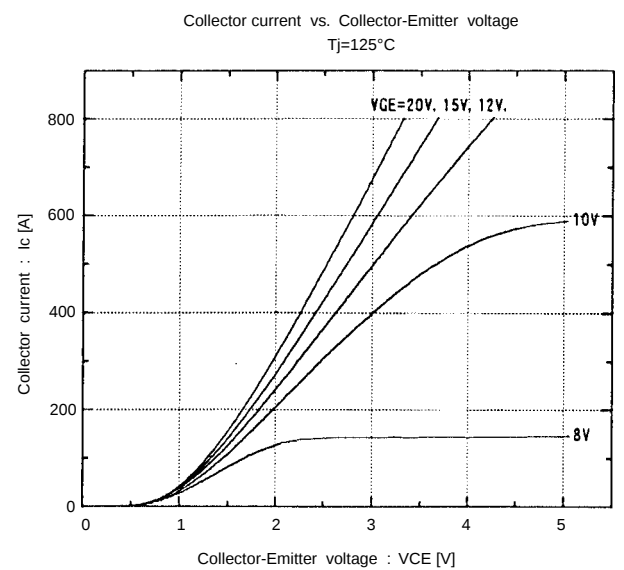
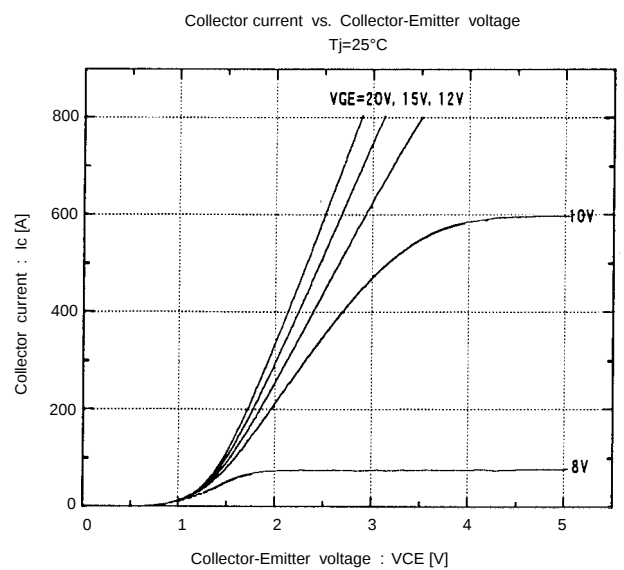


VCE(sat) classification

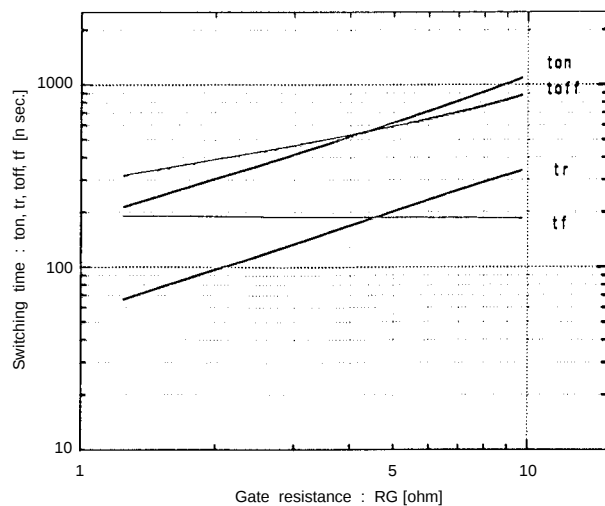
Rank	Lenge	Conditions
F	1.85 to 2.10V	I _C = 400A V _{GE} = 15V T _j = 25°C
A	2.00 to 2.25V	
B	2.15 to 2.40V	
C	2.30 to 2.60V	
D	2.50 to 2.80V	



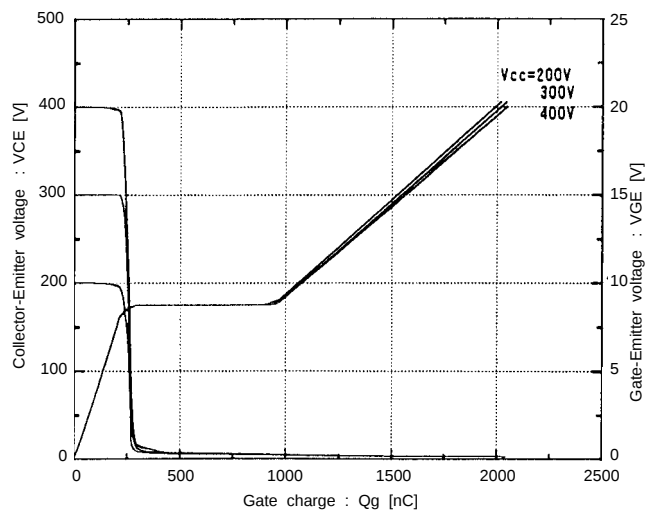
■ Characteristics (Representative)



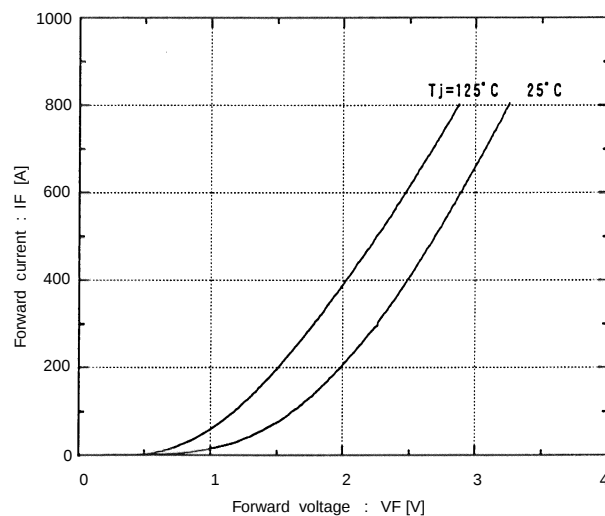
Switching time vs. R_G
 $V_{CC}=300V$, $I_C=400A$, $V_{GE}=\pm 15V$, $T_J=25^\circ C$



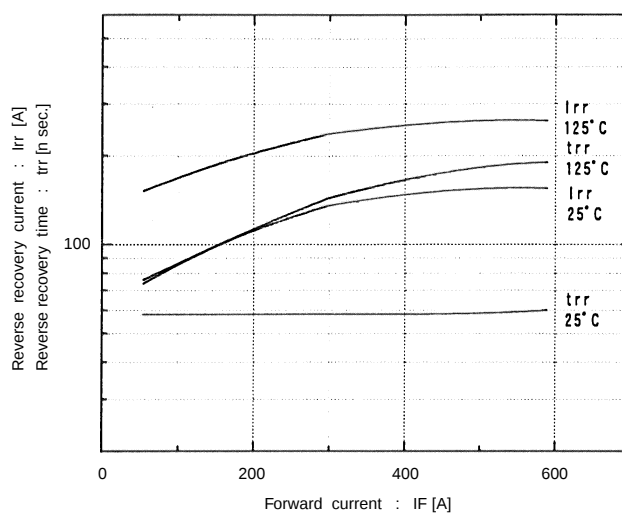
Dynamic input characteristics
 $T_J=25^\circ C$



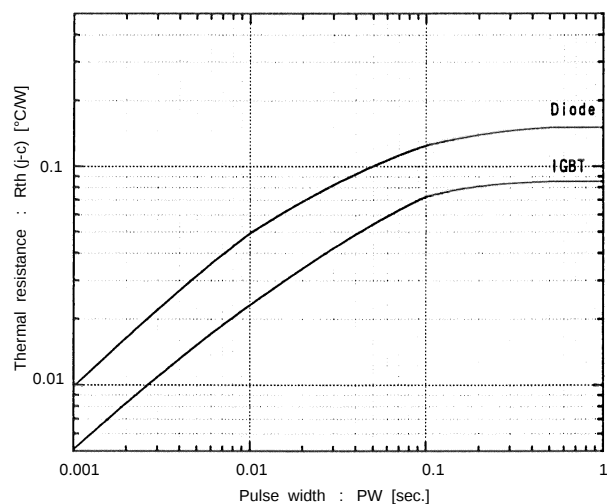
Forward current vs. Forward voltage
 $V_{GE}=0V$



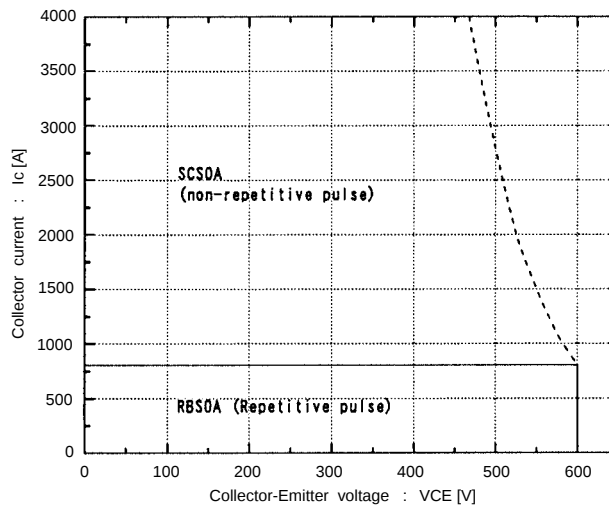
Reverse recovery characteristics
 t_{rr} , I_{rr} , vs. I_F

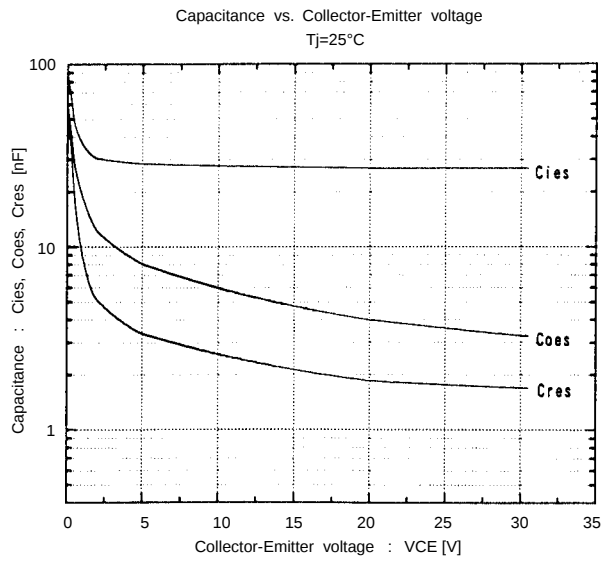
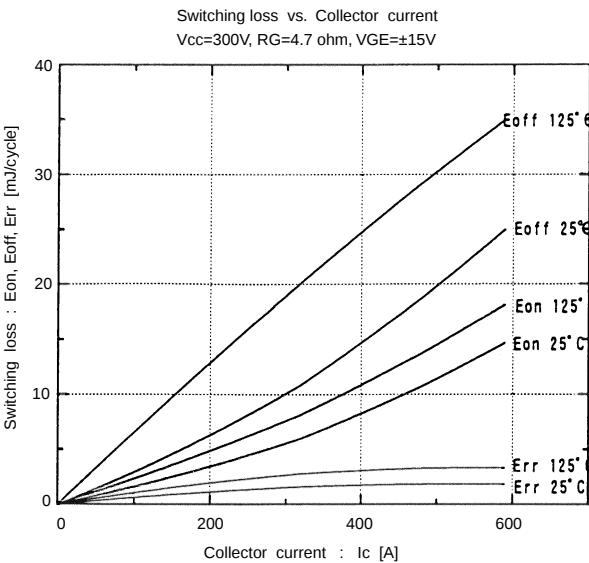


Transient thermal resistance

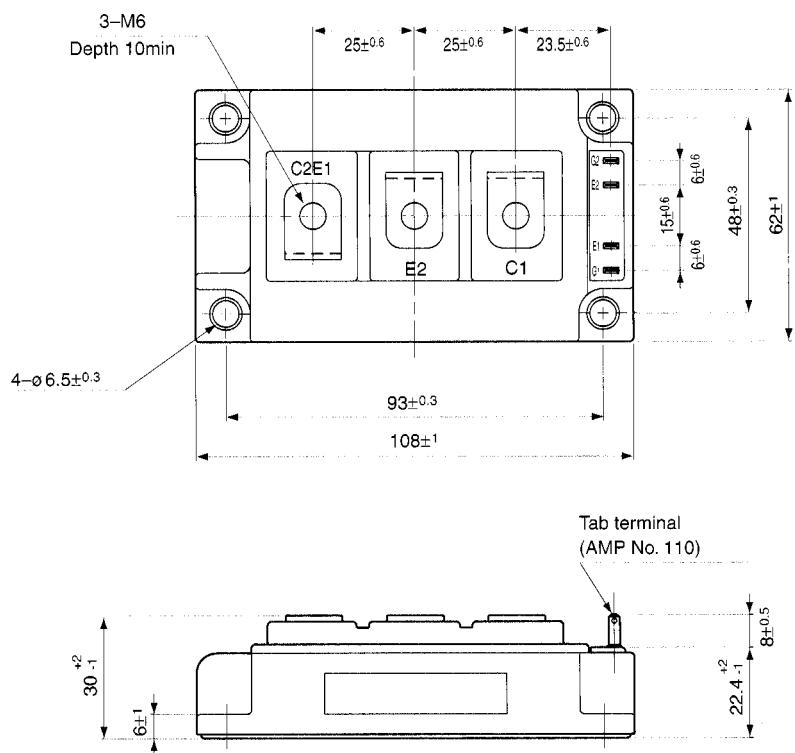


Reversed biased safe operating area
 $+V_{GE}=15V$, $-V_{GE} \leq 15V$, $T_J \leq 125^\circ C$, $R_G \geq 4.7 \text{ ohm}$





■ Outline Drawings, mm



Mass : 370g